

V _{RSM}	V _{RRM}	(dv/dt) _{cr}	I _{TRMS} (maximum values for continuous operation)			
			240 A	270 A	240 A	270 A
V	V	V/μs	I _{TAV} (sin. 180; T _{case} = . . .)			
			150 A (85 °C)	172 A (81 °C)	150 A (85 °C)	172 A (81 °C)
			SKKT	SKKT	SKKH	SKKH
900	800	500	131/08 D	161/08 D	131/08 D	161/08 D
1300	1200	1000	131/12 E	161/12 E	131/12 E	161/12 E
1500	1400	1000	131/14 E	161/14 E	131/14 E	161/14 E
1700	1600	1000	131/16 E	161/16 E	131/16 E	161/16 E
1900	1800	1000	131/18 E	161/18 E	131/18 E	161/18 E
2100	2000	1000	131/20 E	–	131/20 E	–
2300	2200	1000	131/22 E	–	131/22 E	–

Symbol	Conditions		SKKT 131 SKKH 131	SKKT 161 SKKH 161	Units
I _{TAV}	sin. 180; T _{case} = 81 °C		–	172	A
	85 °C		150	160	A
	92 °C		130	–	
I _D	B2/B6	T _{amb} P 16/170 F	295/375	325/410	A
		= P 16/200 F	300/380	330/415	A
		P 16/300 F	– /390	– /425	A
I _{RMS}	W1/W3	35 °C; P 16/170 F	340/3x290	380/3x310	A
		P 16/200 F	385/3x312	385/3x337	A
		P 16/300 F	– /3x318	– /3x344	A
I _{TSM}	T _{vj} = 25 °C; 10 ms		4 700	5 400	A
	T _{vj} = 130 °C; 10 ms		4 000	5 000	A
i ² t	T _{vj} = 25 °C; 8,3 ... 10 ms		110 000	145 000	A ² s
	T _{vj} = 130 °C; 8,3 ... 10 ms		80 000	125 000	A ² s
t _{gd}	T _{vj} = 25 °C; I _G = 1 A				
	di _G /dt = 1 A/μs		1		μs
t _{gr}	V _D = 0,67 · V _{DRM}		2		μs
(di/dt) _{cr}	T _{vj} = 130 °C		200		A/μs
t _q	T _{vj} = 130 °C		typ. 50 ... 150		μs
I _H	T _{vj} = 25 °C; typ./max.		150 / 400		mA
I _L	T _{vj} = 25 °C; R _G = 33 Ω; typ./max.		0,3 / 1		A
V _T	T _{vj} = 25 °C; I _T = 500 A		max. 1,7	max. 1,55	V
V _{T(TO)}	T _{vj} = 130 °C		1	1	V
r _T	T _{vj} = 130 °C		1,4	1,0	mΩ
I _{DD} ; I _{RD}	T _{vj} = 130 °C; V _{RD} = V _{RRM} V _{DD} = V _{DRM}		max. 50	max. 50	mA
V _{GT}	T _{vj} = 25 °C; d.c.		3		V
I _{GT}	T _{vj} = 25 °C; d.c.		150		mA
V _{GD}	T _{vj} = 130 °C; d.c.		0,25		V
I _{GD}	T _{vj} = 130 °C; d.c.		10		mA
R _{thjc}	cont.		0,19 / 0,09		°C/W
	sin. 180		0,20 / 0,10		°C/W
	rec. 120		0,22 / 0,11		°C/W
R _{thch}	} per thyristor / per module		0,06 / 0,03		°C/W
T _{vj} , T _{stg}			– 40 ... + 130		°C
V _{isol}	a. c. 50 Hz; r.m.s; 1 s/1 min		3600 / 3000		V~
M ₁	} SI (US) units to heatsink to terminals		5 (44 lb. in.) ± 15 % ¹⁾		Nm
M ₂			9 (80 lb. in.) ± 15 % ²⁾		Nm
a			5 · 9,81		m/s ²
w	approx.		820		g
Case	→ page B 1 – 74		SKKT: A 13 SKKH: A 14		

SEMIPACK® 3

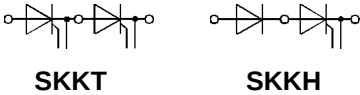
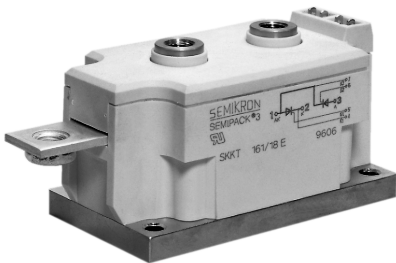
Thyristor / Diode Modules

SKKT 131

SKKH 131

SKKT 161

SKKH 161



- Features

 - Heat transfer through aluminium nitride ceramic isolated metal baseplate
 - Precious metal pressure contacts for high reliability
 - UL recognized, file no. E 63 532

- Typical Applications

 - DC motor control (e.g. for machine tools)
 - Temperature control (e.g. for ovens, chemical processes)
 - Professional light dimming (studios, theaters)

1) See the assembly instructions

2) The screws must be lubricated

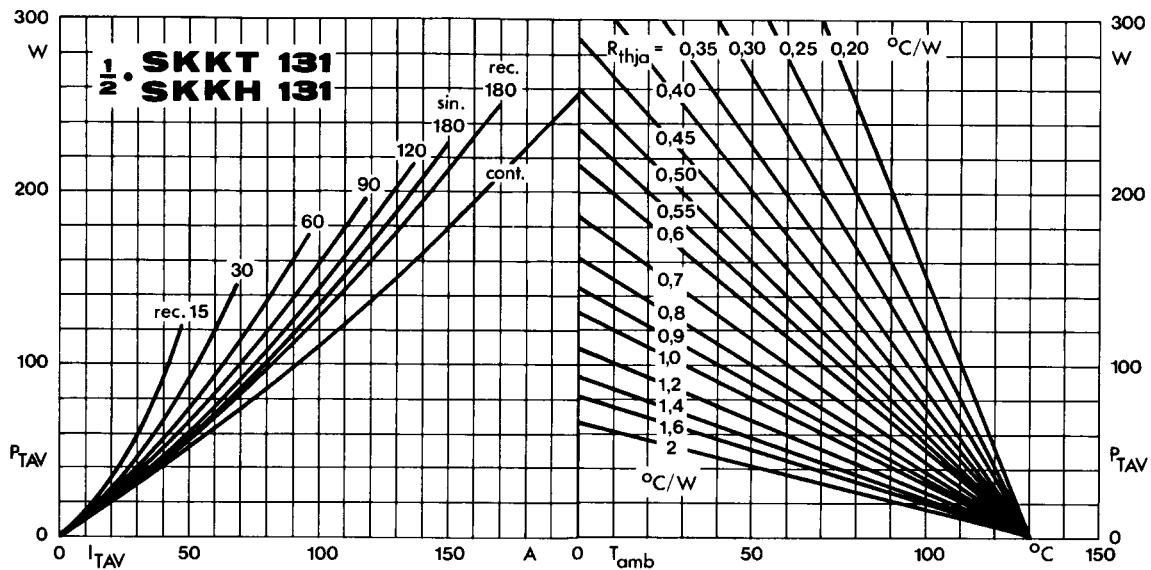


Fig. 1 a Power dissipation per thyristor vs. on-state current and ambient temperature

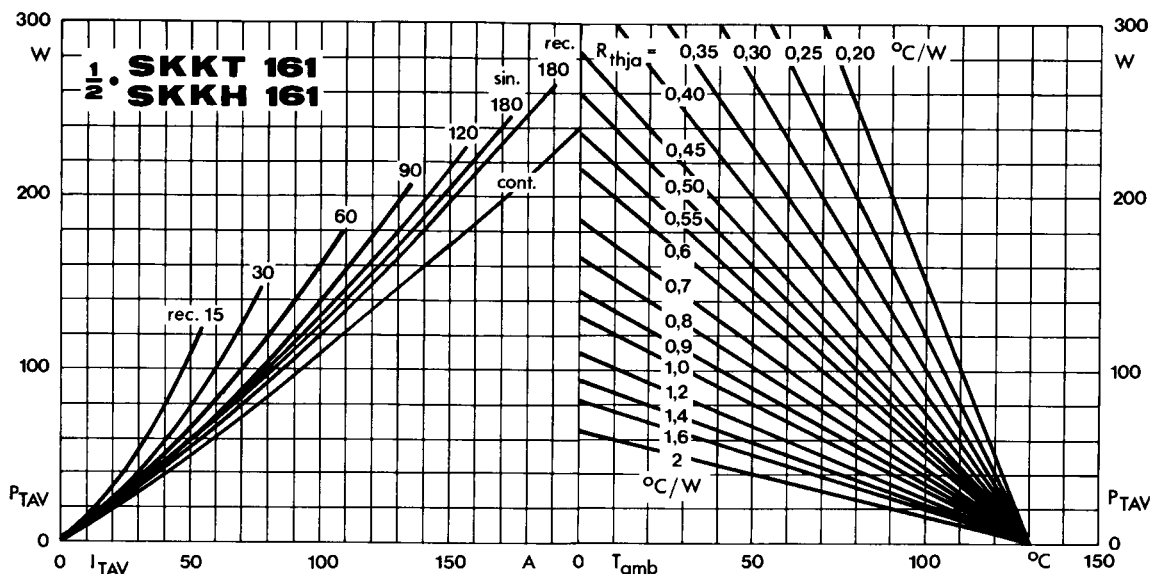


Fig. 1 b Power dissipation per thyristor vs. on-state current and ambient temperature

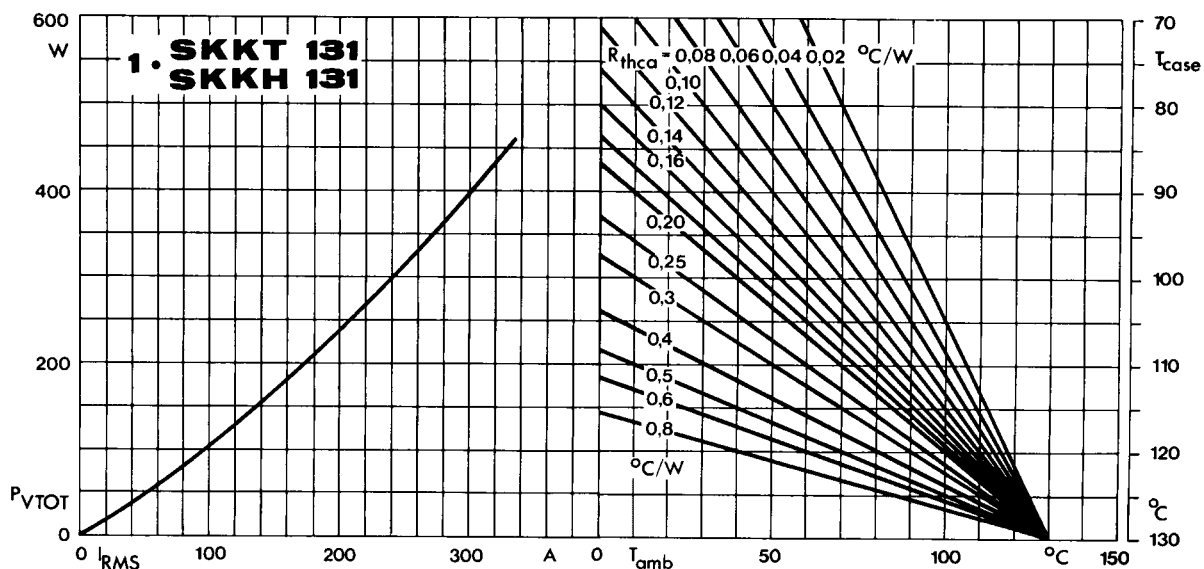


Fig. 2 a Power dissipation per module vs. rms current and case temperature

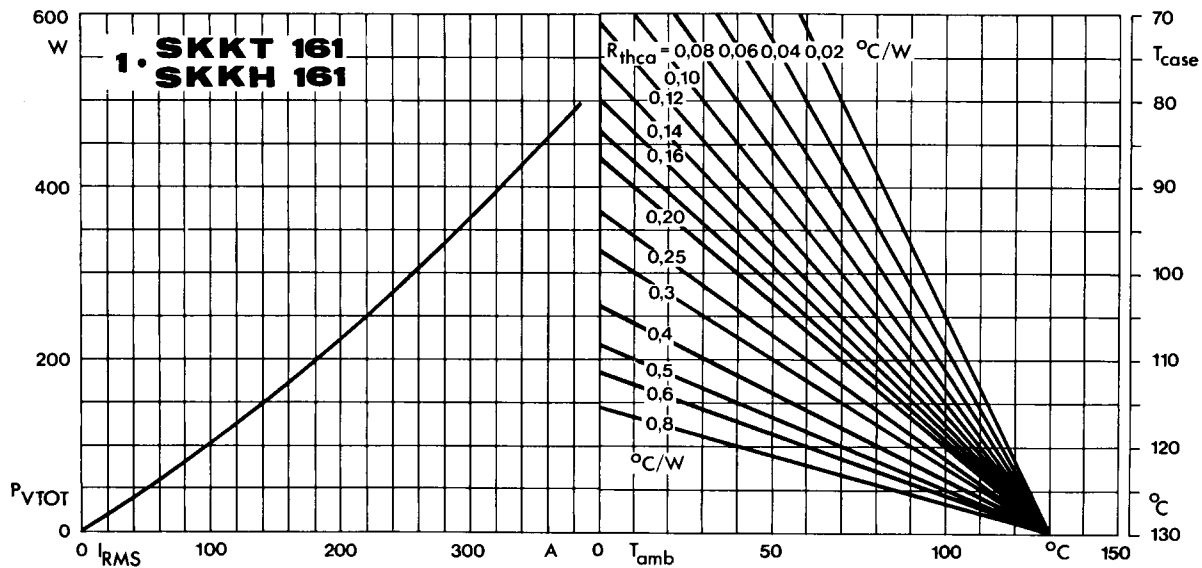


Fig. 2 b Power dissipation per module vs. rms current and case temperature

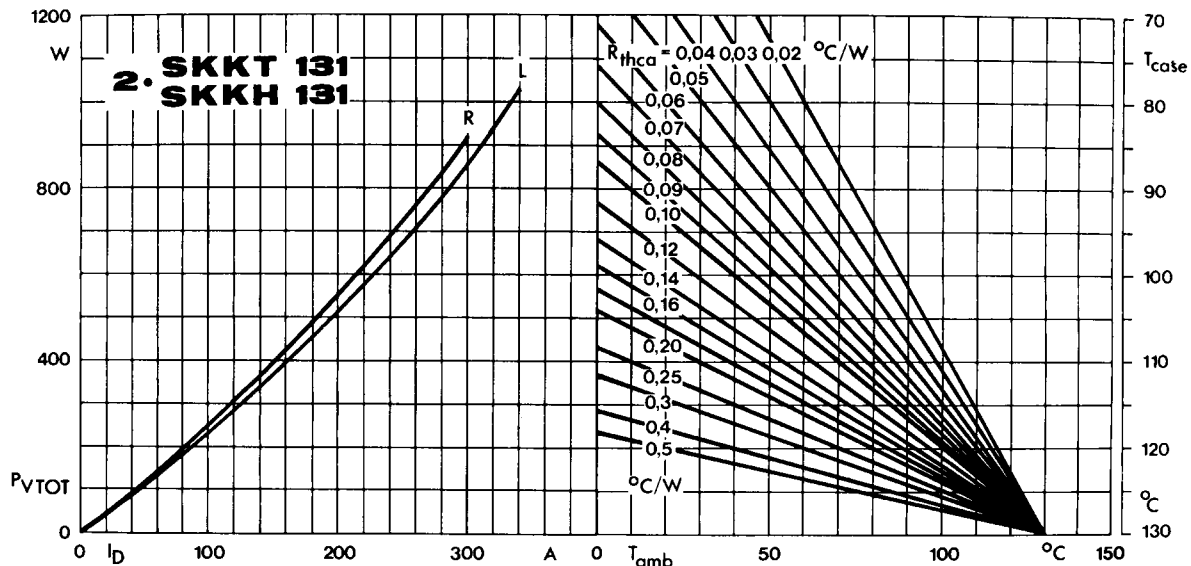


Fig. 3 a Power dissipation of two modules vs. direct current and case temperature

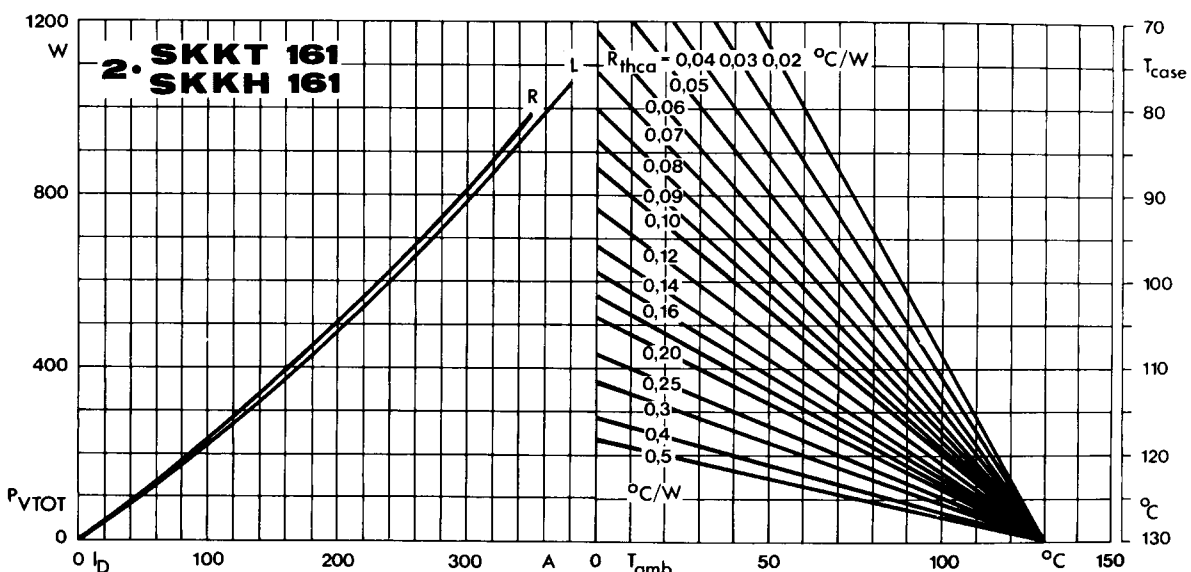


Fig. 3 b Power dissipation of two modules vs. direct current and case temperature

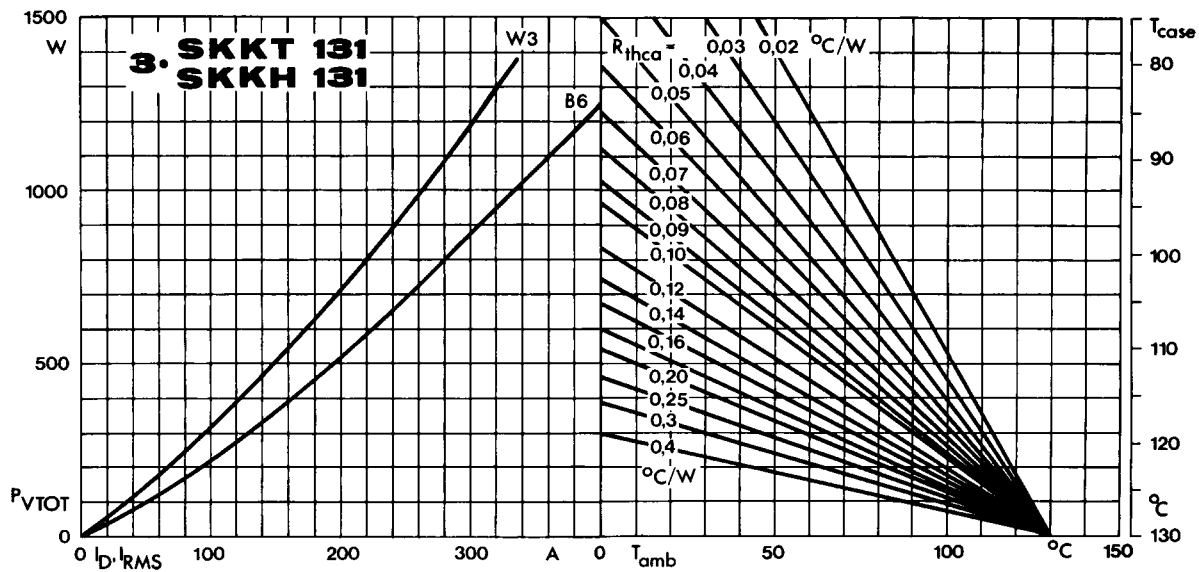


Fig. 4 a Power dissipation of three modules vs. direct and rms current and case temperature

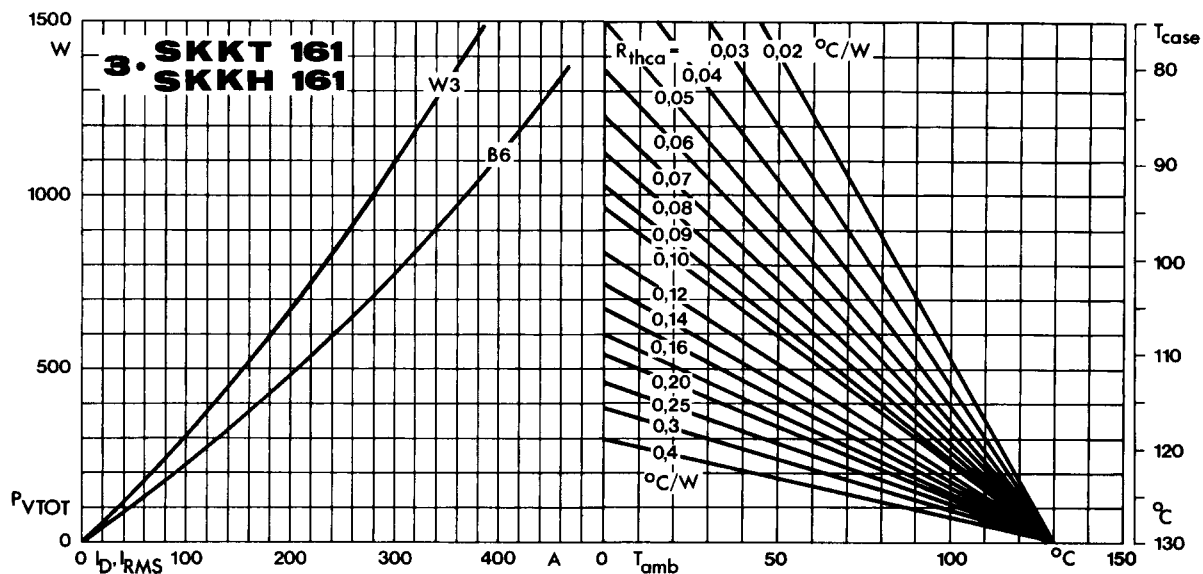


Fig. 4 b Power dissipation of three modules vs. direct and rms current and case temperature

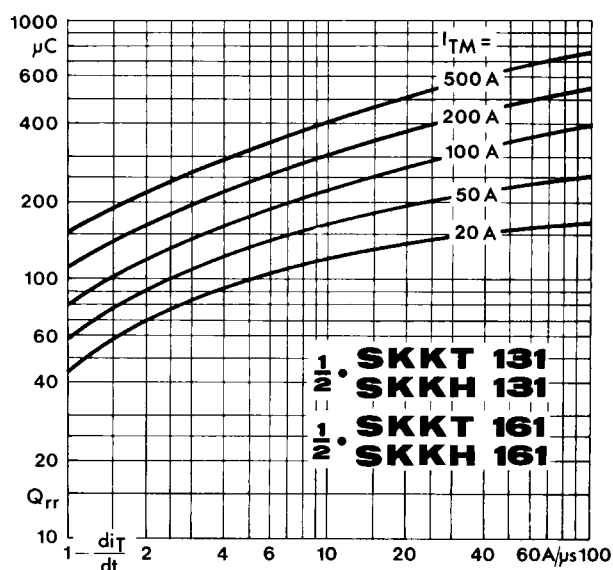


Fig. 5 Recovered charge vs. current decrease

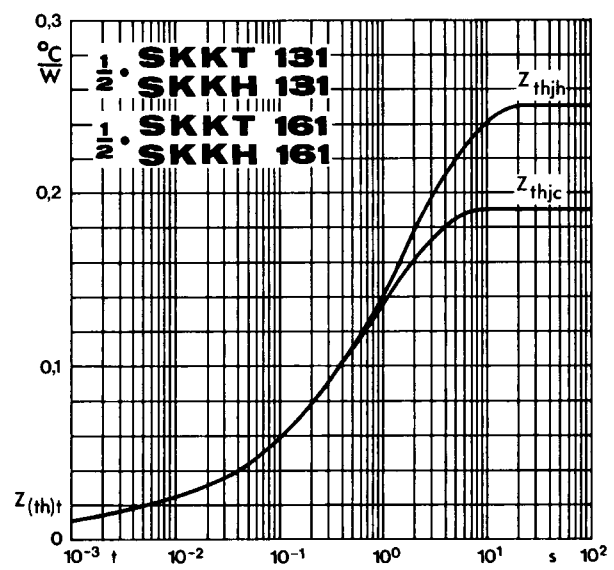


Fig. 6 Transient thermal impedance vs. time

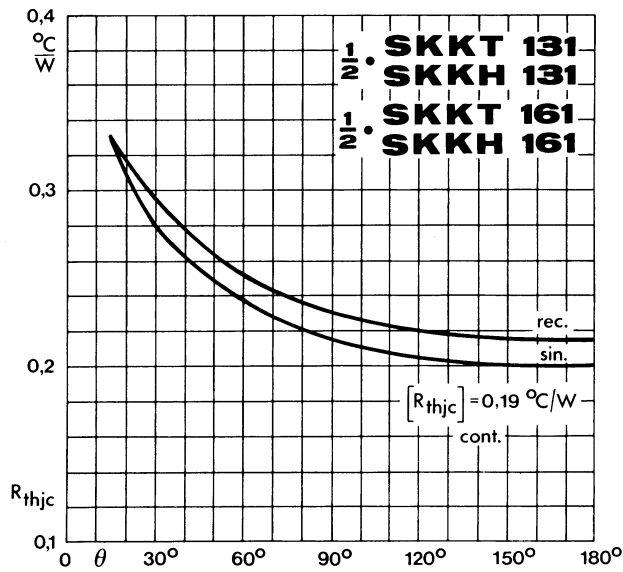


Fig. 7 Thermal resistance vs. conduction angle

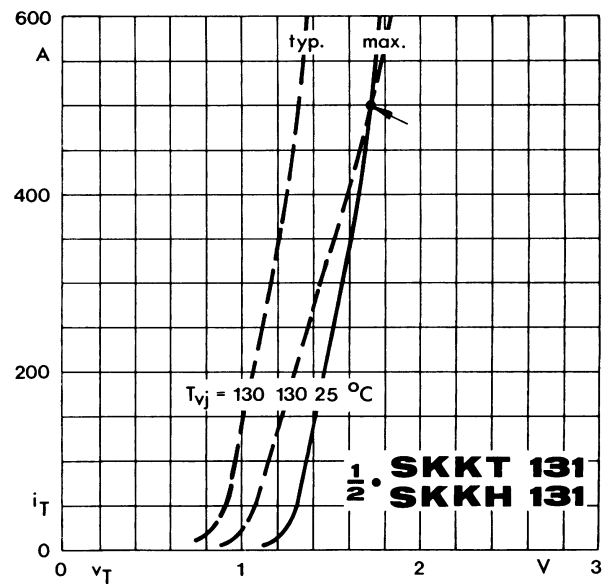


Fig. 8 a On-state characteristic

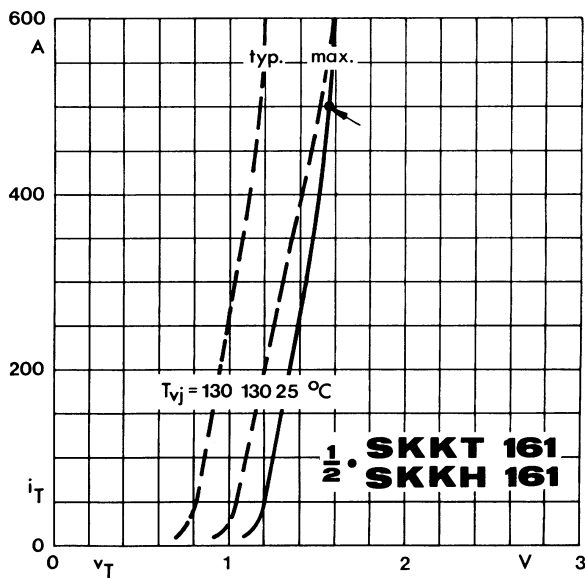


Fig. 8 b On-state characteristics

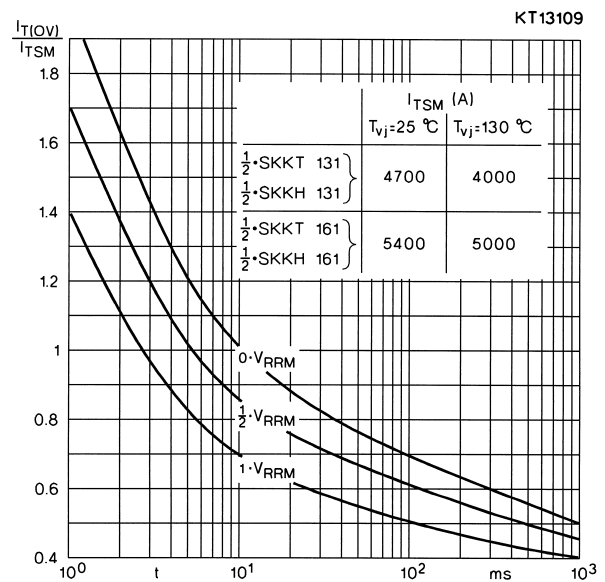


Fig. 9 Surge overload current vs. time

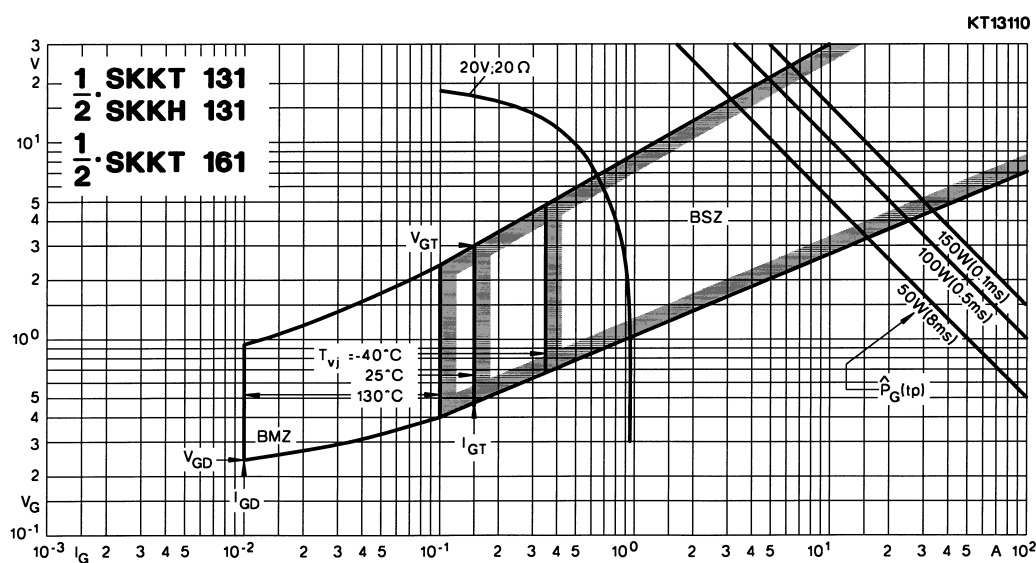


Fig. 10 Gate trigger characteristics

UL recognized, file no. E 63 532

